

Description

The 74LVC1G04 is a single inverter gate with a standard push-pull output. The device is designed for operation with a power supply range of 1.65V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF}. The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

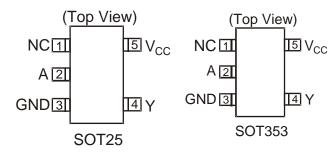
The gate performs the positive Boolean function:

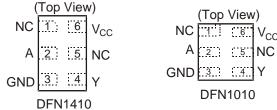
$$Y = \overline{A}$$

Features

- Wide Supply Voltage Range from 1.65 to 5.5V
- ± 24mA Output Drive at 3.3V
- CMOS low power consumption
- I_{OFF} Supports Partial-Power-Down Mode Operation
- Inputs accept up to 5.5V
- ESD Protection Tested per JESD 22
 - o Exceeds 200-V Machine Model (A115-A)
 - Exceeds 2000-V Human Body Model (A114-A)
 - o Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- Range of Package Options
- Direct Interface with TTL Levels
- All packages Assembled with "Green" Molding Compound (no Br, Sb)
- Lead Free Finish/ RoHS Compliant (Note 1)

Pin Assignments





Applications

- Voltage Level Shifting
- General Purpose Logic
- Power Down Signal Isolation
- Wide array of products such as.
 - o PCs, networking, notebooks, netbooks, PDAs
 - o Tablet Computers, E-readers
 - o Computer peripherals, hard drives, CD/DVD ROM
 - o TV, DVD, DVR, set top box
 - o Cell Phones, Personal Navigation / GPS
 - MP3 players ,Cameras, Video Recorders

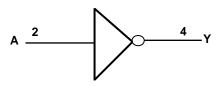
Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead_free.html



Pin Descriptions

Pin Name	Description	
NC	No Connection	
Α	Data Input	
GND	Ground	
Y	Data Output	
V _{CC}	Supply Voltage	

Logic Diagram



Function Table

Inputs	Output
Α	Y
Н	L
L	Н

Absolute Maximum Ratings (Note 2)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	٧
V _{CC}	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high impedance or I _{OFF} state	-0.5 to 6.5	V
Vo	Voltage applied to output in high or low state.	-0.3 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current V _I <0	-50	mA
lok	Output Clamp Current	-50	mA
I _O	Continuous output current	±50	mA
I _{CC,} I _{GN}	Continuous current through Vcc or GND	±100	mA
TJ	Operating Junction Temperature	-40 to 150	°C
T _{STG}	Storage Temperature	-65 to 150	°C

Notes: 2. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 3)

Symbol		Parameter	Min	Max	Unit
\/	Operating Voltage	Operating	1.65	5.5	V
V _{CC}	Operating voltage	Data retention only	1.5		V
	High-level Input Voltage	V _{CC} = 1.65V to 1.95V	0.65 X V _{CC}		
V		$V_{CC} = 2.3V \text{ to } 2.7V$	1.7		\/
V_{IH}		$V_{CC} = 3V$ to 3.6V	2		V
		$V_{CC} = 4.5V \text{ to } 5.5V$	0.7 X V _{CC}		
		V _{CC} = 1.65V to 1.95V		0.35 X V _{CC}	
V_{IL}	Low-level input voltage	V _{CC} = 2.3V to 2.7V		0.7	\/
		$V_{CC} = 3V$ to 3.6V		0.8	V
		V _{CC} = 4.5V to 5.5V		0.3 X V _{CC}	
VI	Input Voltage		0	5.5	V
Vo	Output Voltage		0	V _{CC}	V
		V _{CC} = 1.65V		-4	
		V _{CC} = 2.3V		-8	
I_{OH}	High-level output current	V 2V		-16	mA
		$V_{CC} = 3V$		-24	
		$V_{CC} = 4.5V$		-32	
		V _{CC} = 1.65V		4	
		$V_{CC} = 2.3V$		8	
I_{OL}	Low-level output current	$V_{CC} = 3V$		16	mA
		VCC = 3V		24	
		$V_{CC} = 4.5V$		32	
	Lancet tono cities air a 100	$V_{CC} = 1.8V \pm 0.15V, 2.5V \pm 0.2V$		20	
$\Delta t/\Delta V$	Input transition rise or fall rate	$V_{CC} = 3.3V \pm 0.3V$		10	ns/V
	Tato	$V_{CC} = 5V \pm 0.5V$		5	
T _A	Operating free-air temperature		-40	125	°C

Notes: 3. Unused inputs should be held at V_{CC} or Ground.



Electrical Characteristics (All typical values are at V_{CC} = 3.3V, T_A = 25°C)

Compleal	Devementar	Took Conditions	V	-40	0°C to 85°	С	-40°C to	125°C	Unit
Symbol	Parameter	Test Conditions	V _{CC}	Min	Тур.	Max	Min	Max	Unit
		I _{OH} = -100μA	1.65V to 5.5V	V _{CC} - 0.1			V _{CC} – 0.1		
		I _{OH} = -4mA	1.65V	1.2			0.95		
\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	High Level	$I_{OH} = -8mA$	2.3V	1.9			1.7		V
V _{OH}	Output Voltage	I _{OH} = -16mA	3V	2.4			2.2		V
	Vollago	I _{OH} = -24mA	3V	2.3			2.0		
		I _{OH} = -32mA	4.5V	3.8			3.4		
		I _{OL} = 100μA	1.65V to 5.5V			0.1		0.1	
		I _{OL} = 4mA	4mA 1.65V			0.45		0.7	
.,	Low Level I _{OL} = 8mA 2.3V	2.3V			0.3		0.45	V	
V _{OL}	Output Voltage	I _{OL} = 16mA	- 3V			0.4		0.6	7 V
	Voltage	I _{OL} = 24mA				0.55		0.8	
		I _{OL} = 32mA	4.5V			0.55		.8	
II	Input Current	V _I = 5.5 V or GND	0 to 5.5V		± 0.1	±5		± 100	μΑ
loff	Power Down Leakage Current	V _I or V _O = 5.5V	0V			±10		±200	μΑ
Icc	Supply Current	$V_I = 5.5V$ or GND $I_O=0$	5.5V		0.1	10		200	μA
ΔI _{CC}	Additional Supply Current	Input at V _{CC} –0.6V	3V to 5.5V			500		5000	μΑ
C _i	Input Capacitance	$V_i = V_{CC} - \text{ or GND}$	3.3V		5				pF



Package Characteristics (All typical values are at V_{CC} = 3.3V, T_A = 25°C)

Symbol	Parameter	Test Conditions	V _{CC}	Min	Тур.	Max	Unit
		SOT25			204		
0	Thermal Resistance	SOT353	(Note 4)		371		°C/W
θ_{JA}	Junction-to-Ambient	DFN1010			445		
		DFN1410			460		
		SOT25			52		
0	Thermal Resistance	SOT35	(NIa+a 4)		143		°C/W
$\theta_{ m JC}$	Junction-to-Case	DFN1010	(Note 4)		250		
		DFN1410			265		

Notes: 4. Test condition for SOT25, SOT353, DFN1410 and DFN1010: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Switching Characteristics

Figure 1 Typical Values at $T_A = 25$ °C and nominal voltages 1.8V, 2.5V, 2.7V, 3.3V, and 5.0V.

Parameter	From	То	V _{CC}	TA	= -40°C to 8	5ºC	$T_A = -40^{\circ}$	C to 125°C	Unit
raiametei	Input	Output	V CC	Min	Тур	Max	Min	Max	Oilit
			1.8V ± 0.15V	1.0	3.0	7.5	1.0	9.5	
			2.5V ± 0.2V	0.5	2.0	5.0	0.5	6.5	
t _{pd}	A or B	Υ	2.7V	0.5	2.3	5.2	0.5	7.0	ns
			$3.3V \pm 0.3V$	0.5	2.0	4.2	0.5	5.5	
			$5.0V \pm 0.5V$	0.5	1.6	3.7	0.5	5.0	

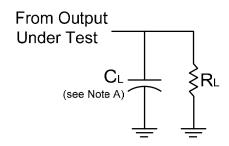
Operating Characteristics

 $T_A = 25 \, {}^{\circ}C$

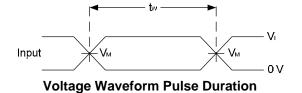
	-д = -	Parameter	Test Conditions	V _{CC} = 1.8V Typ.	V _{CC} = 2.5V Typ.	V _{CC} = 3.3V Typ.	V _{CC} = 5V Typ.	Unit
	C_pd	Power dissipation capacitance	f = 10 MHz	16	16	16	16	pF

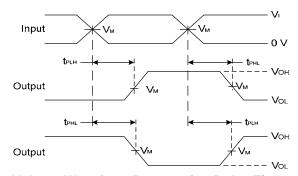


Parameter Measurement Information



V _{CC}	In	puts	V _M	CL	RL
• 66	VI	t _r /t _f	₹ IVI	O _L	IVL
1.8V ± 0.15V	V _{CC}	≤2ns	V _{CC} /2	30 pF	1 ΚΩ
2.5V ± 0.2V	V _{CC}	≤2ns	V _{CC} /2	30 pF	500 Ω
2.7V	V _{CC}	≤2.5ns	1.5V	50 pF	500 Ω
3.3V ± 0.3V	3.0 V	≤2.5ns	1.5V	50 pF	500 Ω
$5.0V \pm 0.5V$	V _{CC}	≤2.5ns	V _{CC} /2	50 pF	500 Ω





Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.

C. t_{PLH} and t_{PHL} are the same as t_{PD}.



Ordering Information

74LVC1G 04 XXX - 7

Package Logic Device **Function Packing** 74: Logic Prefix 7: Tape & Reel 04: 1-Input W5: SOT25

SE: SOT353 LVC: 1.65 to 5.5V Inverter -Gate Family FW4: DFN1010 1G: One gate FZ4: DFN1410

Device	Package	Packaging	7" Tape and Reel		
Device	Code	(Note 6)	Quantity	Part Number Suffix	
74LVC1G04W5-7	W5	SOT25	3000/Tape & Reel	-7	
 74LVC1G04SE-7	SE	SOT353	3000/Tape & Reel	-7	
74LVC1G04FW4-7	FW4	DFN1010	5000/Tape & Reel	-7	
74LVC1G04 FZ4-7	FZ4	DFN1410	5000/Tape & Reel	-7	

Notes:

- 5. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
 6. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf

Marking Information

(1) SOT25 and SOT353

(Top View)

XX Y W X

1 2

XX: Identification Code

<u>Y</u>: Year 0~9

W : Week : A~Z : 1~26 week; a~z: 27~52 week; z represents 52 and 53 week

X: A~Z: Internal Code

Part Number	Package	Identification Code
74LVC1G04W5	SOT25	UU
74LVC1G04SE	SOT353	UU

(2) DFN1010 and DFN1410

(Top View)

XX: Identification Code Y : Year 0~9



 $\overline{\underline{W}}$: Week : A~Z : 1~26 week; a~z: 27~52 week; z represents 52 and 53 week

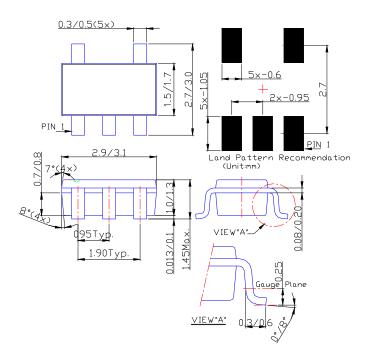
X: A~Z: Internal Code

Part Number	Package	Identification Code
74LVC1G04FW4	DFN1010	UU
74LVC1G04FZ4	DFN1410	UU

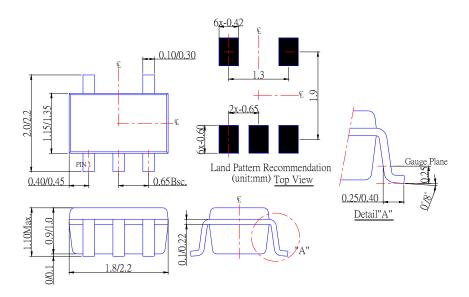


Package Outline Dimensions (All Dimensions in mm)

(1) Package Type: SOT25



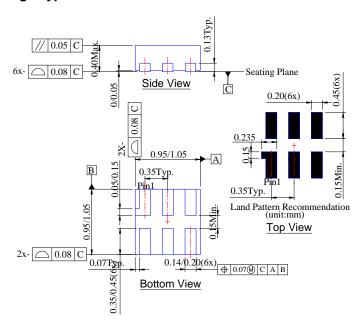
(2) Package Type: SOT353



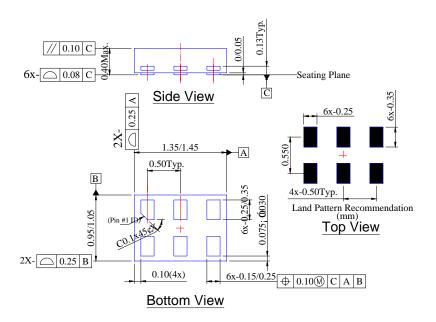


Package Outline Dimensions (cont.)

(3) Package Type DFN1010



(4) Package Type: DFN1410





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